

Knowing that  $x$  depends on  $g$  and  $x \ll d_0$  then, the simulation of sensitivity as a function of movable mass displacement is given in Figure.10:

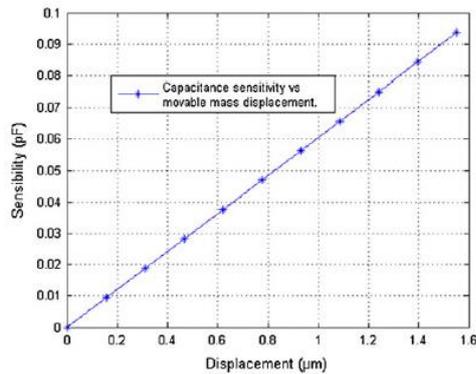


Figure.10.

We note that the difference in capacity is extremely sensitive at the minimum displacement of the mobile fingers that explains the effectiveness of the model.

### 10.3 Capacitance sensitivity $S_c = f(g)$

A graphics presentation of capacitance sensitivity as a function of acceleration with the 0g basis up to 5g, is shown in Figure.11.

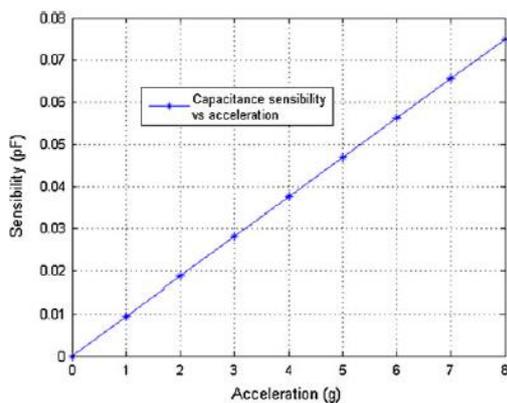


Figure.11.

It is clear that the accelerations increase implies an increase in the capacitance sensitivity  $S_c$ ; this proves that one can count on this model to obtain a high precision sensitivity.

## 11. Conclusion

After the results obtained by simulation of some parameters accelerometer capacitive, we note that the geometry of the component such as the width and the length of the mobile fingers as those of spring take a very important role on the acceleration sensitivity.

Theoretically, we can narrow down the beam width  $W_b$  to achieve very high device sensitivity. However, there is always a bottom limit for the beam width set by the minimum line width in a fabrication process. If the beam width is too narrow less than  $2\mu\text{m}$ , it will become very challenging to fabricate the beam because the beam is extremely fragile and can be easily broken.

Therefore, to obtaining a good performance and a good sensitivity of a capacitive accelerometer, it is necessary to choose better parameters such as the beam width and the beam length ( $W_b$  and  $L_b$ ) which represents the suspension of the acceleration system.

Other share, the mobile fingers width and length ( $W_f$  and  $L_f$ ) which constitute the capacities between the mobile fingers and the fixed fingers influence directly the value of these capacities then acceleration, which requires a choice very precise of these parameters.

## References

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